ASSP

CMOS

FRONT-END LSI

MB54501

■ DESCRIPTION

The Fujitsu MB54501 includes a low-noise amplifier and a mixer, which are used for front end of mobile telecommunication systems.

Using Fujitsu's advanced technology, MB54501 achieves an Icc of 6.0mA (typ.).

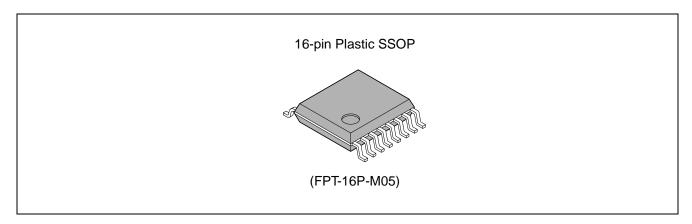
■ FEATURES

	Amplifier	Mixer
 Supply voltage 	3V (typ.)	3V (typ.)
 Current consumption 	3mA (typ.)	3mA (typ.)
 Input frequency 	1.1GHz (max.)	1.1GHz (max.)
Gain	14dB (typ.)*1	15dB (typ.)*2
Noise figure	2.2dB (typ.)*1	5dB (SSB, typ.)*2
1dB compression point	-1dBm (typ.)*1	
Input return loss	8dB (typ.)*1	
Output return loss	10dB (typ.)*1	
*1: Measured by the circuit (fin = 878MHz)	of "measurement cir	cuit example".
*2: Measured by the circuit	of "measurement cir	cuit example".

• 16-pin Plastic Shrink Small Outline Package (Suffix: -PFV)

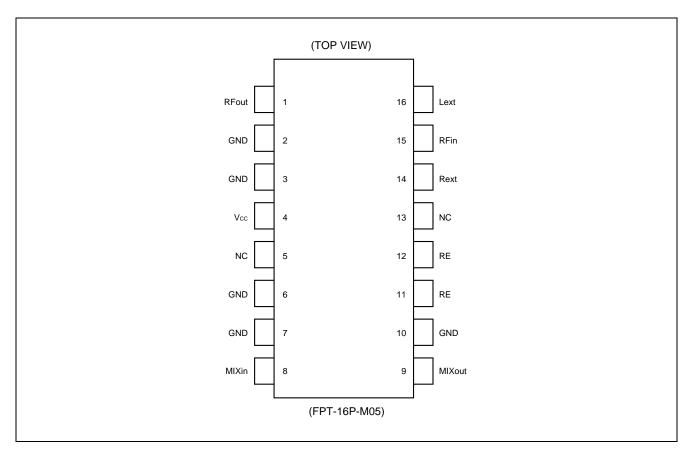
■ PACKAGE

(IF = 90MHz)



MB54501

■ PIN ASSIGNMENT

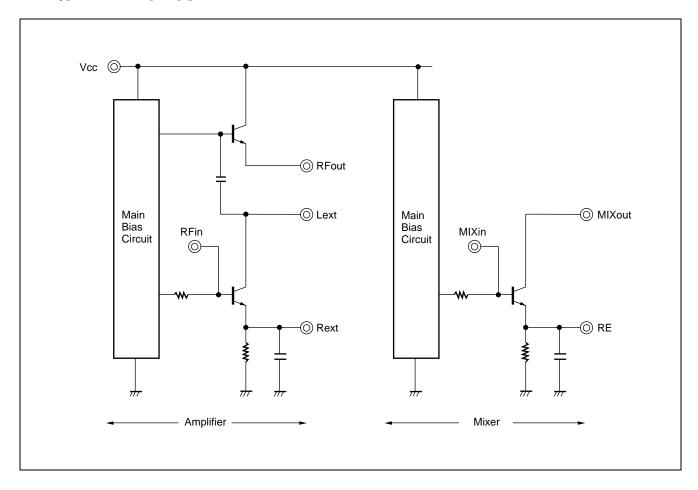


■ ABSOLUTE MAXIMUM RATINGS

Parameters	Symbol	Value	Unit
Supply Voltage	Vcc	-0.5 to 7.0	V
Output Voltage	Vo	-0.5 to Vcc + 0.5	V
Output Current	lo	0 to 10	mA
Storage Temperature	Тѕтс	-55 to +125	°C

Note: Permanent device damage may occur if the above Absolute Maximum Ratings are exceeded. Functional operation should be restricted to the conditions as detailed in the operational sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

■ EQUIVALENT CIRCUIT



■ PIN DESCRIPTION

Pin No.	Pin Name	Description	Pin No.	Pin Name	Description	
1	RFout	Amplifier output	9	MIXout	Mixer output	
2	GND	Ground	10	GND	Ground	
3	GND	Ground	11	RE	Emitter of a transistor for mixer	
4	Vcc	Power supply	12	KE	Emilier of a transistor for mixer	
5	NC	No connection	13	NC	No connection	
6	GND	Ground	14	Rext	Emitter of a transistor for amplifier	
7	GND	Ground	15	RFin	Amplifier input	
8	MIXin	Mixer input	16	Lext	Amplifier load connection	

MB54501

■ RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol		Unit		
Parameter	Symbol	Min.	Тур.	Max.	Offic
Supply Voltage	Vcc	2.7	3.0	5.5	V
Input Voltage	Vı	GND	_	Vcc	V
Operating Temperature	Та	-40	_	+85	°C

Notes: To protect against damage by electrostatic discharge, note the following handling precautions:

- Store and transport devices in conductive containers.
- Use properly grounded workstations, tools, and equipment.
- Turn off power before inserting or removing this device into or from a socket.
- Protect leads with conductive sheet, when transporting a board mounted device.

■ ELECTRICAL CHARACTERISTICS

AMPLIFIER

 $(Vcc = +3.0V, Ta = 25^{\circ}C)$

Parameter	Symbol	Conditions	Target Value			l lmi4
			Min.	Тур.	Max.	Unit
Supply Voltage	Vcc	_	2.7	3.0	5.5	V
Supply Current	Icc			3.0		mA
Operating Frequency	fin			878	1100	MHz
Gain	Gain	_		14	_	dB
Noise Figure	NF	_		2.2	_	dB
1dB Compression Point	P _{1dB}	Output		-1		dBm
Input Return Loss	RLin	_		8	_	dB
Output Return Loss	RLout	_		10	_	dB

Remark: Electrical characteristics depend on external circuits (elements) or status of mounting. The above characteristics are measured by the test circuit in the next page.

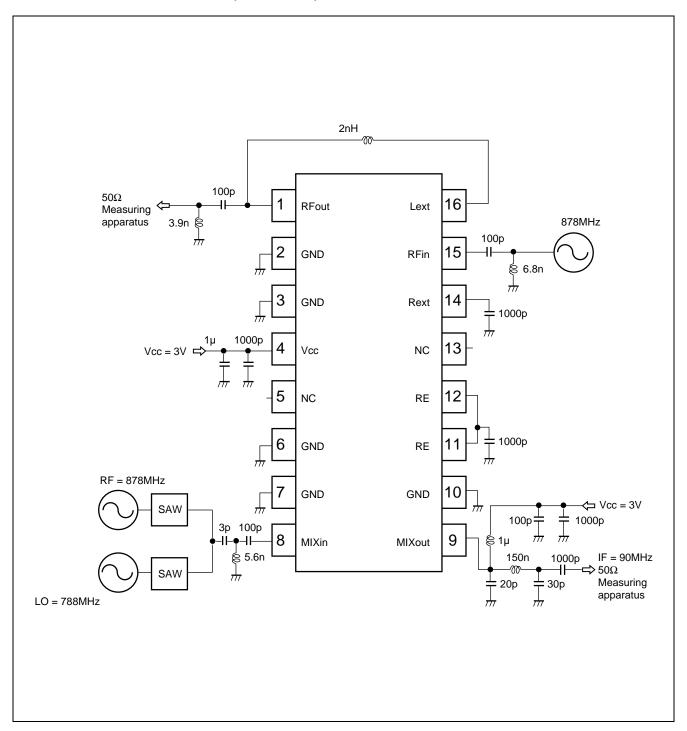
MIXER

 $(Vcc = +3.0V, Ta = 25^{\circ}C)$

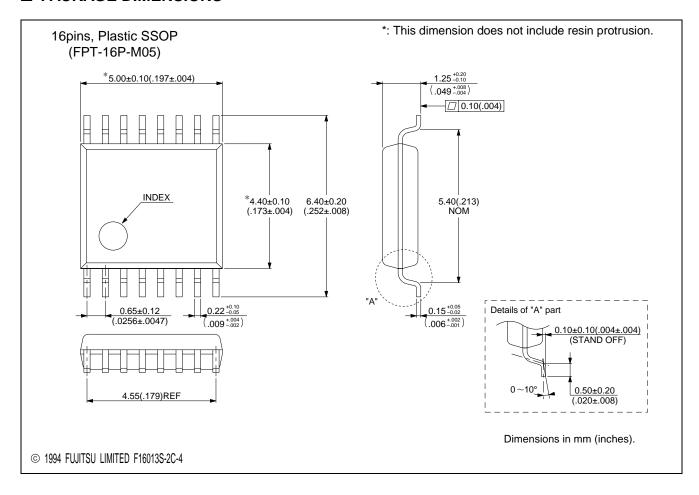
Parameter	Symbol	Conditions -		Target Value			Unit
Parameter	Symbol			Min.	Тур.	Max.	Onit
Supply Voltage	Vcc			2.7	3.0	5.5	V
Current Consumption	Icc	_			3.0		mA
Operating Frequency	fin				878	1100	MHz
Gain	S ₂₁	Amplifier characteristics		_	9	_	dB
Conversion Gain	Gc	Mixer		_	15	_	dB
Noise Figure	NF	characteristics IF = 90MHz	SSB		5		dB

Remark: Electrical characteristics depend on external circuits (elements) or status of mounting. The above characteristics are measured by the test circuit in the next page.

■ MEASUREMENT CIRCUIT (EXAMPLE)



■ PACKAGE DIMENSIONS



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